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# HAT2143H

# Silicon N Channel Power MOS FET Power Switching

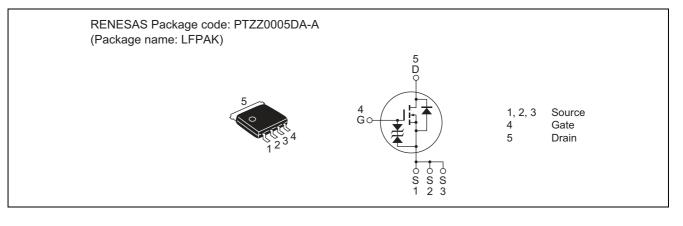
REJ03G1195-0300 (Previous: ADE-208-1584A) Rev.3.00 Sep 07, 2005

### Features

- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance

 $R_{DS (on)} = 4.9 \text{ m}\Omega \text{ typ.} (at V_{GS} = 10 \text{ V})$ 

### Outline





# **Absolute Maximum Ratings**

			$(Ta = 25^{\circ}C)$
Item	Symbol	Value	Unit
Drain to source voltage	V <sub>DSS</sub>	30	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	ID	40	А
Drain peak current	I <sub>D (pulse)</sub> Note 1	160	А
Body-drain diode reverse drain current	I <sub>DR</sub>	40	А
Avalanche current	I <sub>AP</sub> Note 3	16	А
Avalanche energy	E <sub>AR</sub> Note 3	25	mJ
Channel dissipation	Pch Note 2	20	W
Channel temperature	Tch	150	٥°
Storage temperature	Tstg	-55 to +150	°C

Notes: 1.  $PW \le 10 \propto s$ , duty cycle  $\le 1\%$ 

2. Tc = 25 °C

3. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

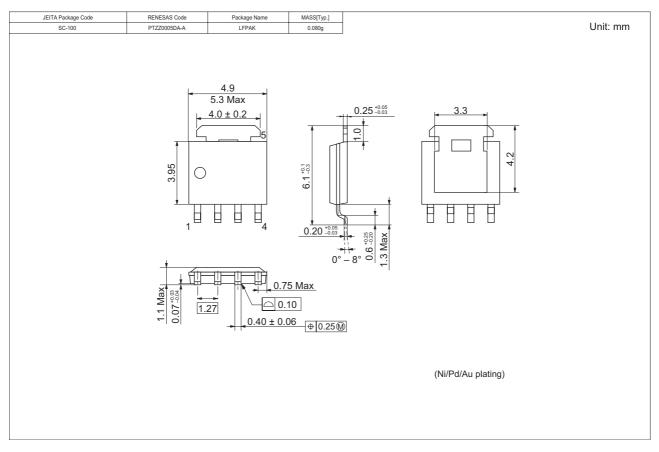
**Electrical Characteristics** 

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V (BR) DSS	30		_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V (BR) GSS	±20		_	V	$I_G = \pm 100 \propto A, V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	—		±10	∝A	$V_{GS} = \pm 16 V, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	—		1	∝A	$V_{DS} = 30 V, V_{GS} = 0$
Gate to source cutoff voltage	V <sub>GS (off)</sub>	1.0		2.5	V	$V_{DS} = 10 V, I_{D} = 1 mA$
Static drain to source on state resistance	R <sub>DS (on)</sub>	—	4.9	6.1	mΩ	$I_D = 20 \text{ A}, V_{GS} = 10 \text{ V}^{Note 4}$
	R <sub>DS (on)</sub>	—	7.9	11.5	mΩ	$I_D = 20 \text{ A}, V_{GS} = 4.5 \text{ V}^{Note 4}$
Forward transfer admittance	y <sub>fs</sub>	30	50	_	S	$I_D = 20 \text{ A}, V_{DS} = 10 \text{ V}^{Note 4}$
Input capacitance	Ciss	—	2450	_	pF	V <sub>DS</sub> = 10 V
Output capacitance	Coss	—	540	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	—	280	_	pF	f = 1 MHz
Total gate charge	Qg	—	40	_	nC	$V_{DD} = 10 V$
Gate to source charge	Qgs	—	8	_	nC	$V_{GS} = 10 V$
Gate to drain charge	Qgd	—	7	_	nC	$I_D = 40 \text{ A}$
Turn-on delay time	t <sub>d (on)</sub>	—	20	_	ns	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$
Rise time	tr	—	56	_	ns	$V_{DD}\cong 10~V$
Turn-off delay time	t <sub>d (off)</sub>	—	76	_	ns	$R_L = 0.5 \Omega$
Fall time	t <sub>f</sub>	—	15	_	ns	Rg = 4.7 Ω
Body-drain diode forward voltage	V <sub>DF</sub>	—	0.85	1.11	V	$I_F = 40 \text{ A}, V_{GS} = 0^{Note 4}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	—	60		ns	$I_F = 40 \text{ A}, V_{GS} = 0$
						$di_F/dt = 50 \text{ A/} \propto s$

Note: 4. Pulse test



## **Package Dimensions**



### **Ordering Information**

Part Name	Quantity	Shipping Container
HAT2143H-EL-E	2500 pcs	Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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